

Absolute Maximum Ratings — Standard Triac

Symbol	Parameter	Value	Unit
$I_{T(RMS)}$	RMS on-state current (full sine wave)	QxXE8y/ QxXy $T_C = 60^\circ\text{C}$	0.8 A
I_{TSM}	Non repetitive surge peak on-state current (full cycle, T_J initial = 25°C)	f = 50 Hz t = 20 ms	8.3 A
		f = 60 Hz t = 16.7 ms	10 A
I^2t	I^2t Value for fusing	$t_p = 8.3$ ms	0.41 A^2s
di/dt	Critical rate of rise of on-state current ($I_G = 200\text{mA}$ with $\leq 0.1\mu\text{s}$ rise time)	f = 120 Hz $T_J = 125^\circ\text{C}$	20 $\text{A}/\mu\text{s}$
I_{GTM}	Peak gate trigger current	$t_p = 10 \mu\text{s};$ $I_{GT} \leq I_{GTM}$ $T_J = 125^\circ\text{C}$	1 A
$P_{G(AV)}$	Average gate power dissipation	$T_J = 125^\circ\text{C}$	0.2 W
T_{stg}	Storage junction temperature range	QxX8Ey	-65 to 150 $^\circ\text{C}$
		QxXy	-40 to 150 $^\circ\text{C}$
T_J	Operating junction temperature range	QxX8Ey	-65 to 125 $^\circ\text{C}$
		QxXy	-40 to 125 $^\circ\text{C}$

Note: x = voltage, y = sensitivity

Electrical Characteristics ($T_J = 25^\circ\text{C}$, unless otherwise specified) — Sensitive Triac (4 Quadrants)

Symbol	Test Conditions	Quadrant	LxX8E3 LxX3	LxX8E5 LxX5	LxX8E6 LxX6	LxX8E8 LxX8	Unit	
I_{GT}	$V_D = 12\text{V}$ $R_L = 30 \Omega$	I – II – III	MAX.	3	5	5	10	mA
		IV	MAX.	3	5	10	20	
V_{GT}	$V_D = 12\text{V}$ $R_L = 30 \Omega$	ALL	MAX.	1.3			V	
V_{GD}	$V_D = V_{DRM}$ $R_L = 3.3 \text{k}\Omega$ $T_J = 110^\circ\text{C}$	ALL	MIN.	0.2			V	
I_H	$I_T = 100\text{mA}$	MAX.	5	10	10	15	mA	
dv/dt	$V_D = V_{DRM}$ Gate Open $T_J = 100^\circ\text{C}$	400V	TYP.	15	15	25	30	$\text{V}/\mu\text{s}$
		600V	TYP.	10	10	20	25	
(dv/dt)c	(di/dt)c = 0.43 A/ms $T_J = 110^\circ\text{C}$	TYP.	0.5	1	1	2	$\text{V}/\mu\text{s}$	
t_{gt}	$I_G = 2 \times I_{GT}$ PW = 15 μs $I_T = 1.13 \text{A(pk)}$	TYP.	2.8	3.0	3.0	3.2	μs	

Electrical Characteristics ($T_J = 25^\circ\text{C}$, unless otherwise specified) — Standard Triac

Symbol	Test Conditions	Quadrant	QxX8E3 QxX3	QxX8E4 QxX4	Unit	
I_{GT}	$V_D = 12\text{V}$ $R_L = 60 \Omega$	I – II – III	MAX.	10	25	mA
		IV	TYP.	25	50	
V_{GT}	$V_D = 12\text{V}$ $R_L = 30 \Omega$	I – II – III	MAX.	1.3	1.3	V
V_{GD}	$V_D = V_{DRM}$ $R_L = 3.3 \text{k}\Omega$ $T_J = 125^\circ\text{C}$	ALL	MIN.	0.2	0.2	V
I_H	$I_T = 200\text{mA}$	MAX.	15	25	mA	
dv/dt	$V_D = V_{DRM}$ Gate Open $T_J = 125^\circ\text{C}$	400V	MIN.	25	35	$\text{V}/\mu\text{s}$
		600V	MIN.	15	25	
(dv/dt)c	(di/dt)c = 0.43 A/ms $T_J = 125^\circ\text{C}$	TYP.	1	1	$\text{V}/\mu\text{s}$	
t_{gt}	$I_G = 2 \times I_{GT}$ PW = 15 μs $I_T = 1.13 \text{A(pk)}$	TYP.	2.5	3.0	μs	

Note: x = voltage

Static Characteristics ($T_J = 25^\circ\text{C}$, unless otherwise specified)

Symbol	Test Conditions		Value	Unit			
V_{TM}	$I_{TM} = 1.13A$ $t_p = 380 \mu s$	MAX.	1.60	V			
I_{DRM} I_{RRM}	$V_{DRM} = V_{RRM}$	MAX.	LxX8Ey / LxXy	$T_J = 25^\circ\text{C}$	400-600V	2	μA
				$T_J = 110^\circ\text{C}$	400-600V	0.1	mA
			QxX8Ey / QxXy	$T_J = 25^\circ\text{C}$	400-600V	5	μA
				$T_J = 125^\circ\text{C}$	400-600V	1	mA

Thermal Resistances

Symbol	Parameter	Value	Unit
$R_{\theta(J-C)}$	Junction to case (AC)	L/QxX8Ey	60
		L/QxXy	60*
$R_{\theta(J-A)}$	Junction to ambient	L/QxX8Ey	135

Note: * = Mounted on 1 cm² 1 copper (two-ounce) foil surface

Figure 1: Definition of Quadrants

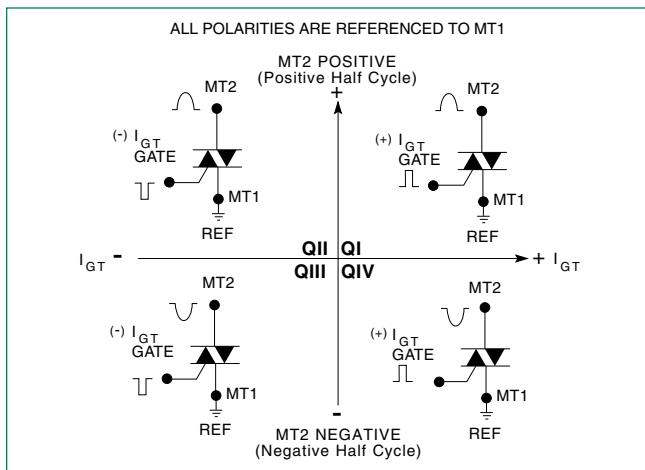


Figure 2: Normalized DC Gate Trigger Current for All Quadrants vs. Junction Temperature

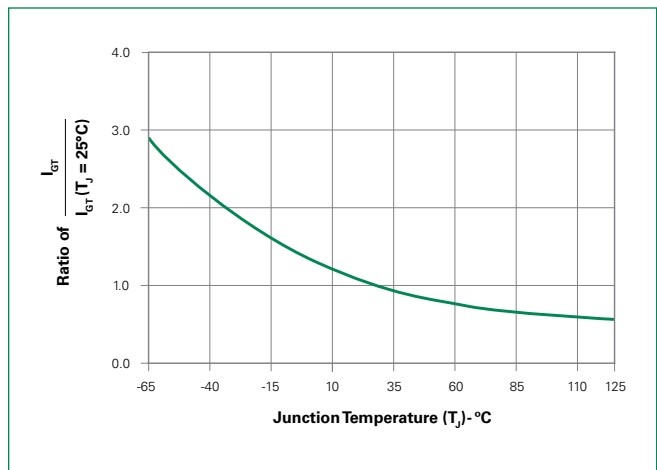


Figure 3: Normalized DC Holding Current vs. Junction Temperature

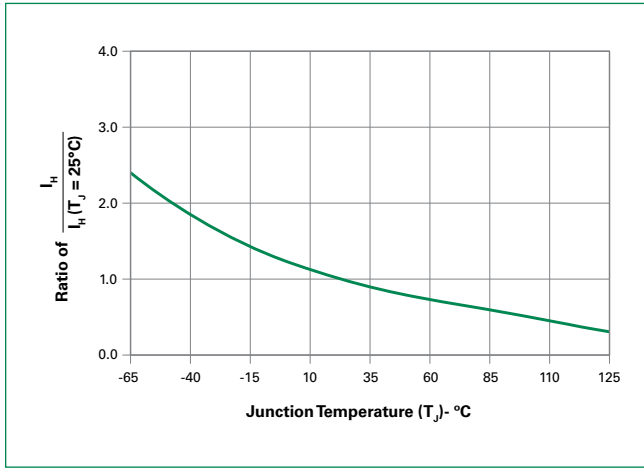


Figure 4: Normalized DC Gate Trigger Voltage for All Quadrants vs. Junction Temperature

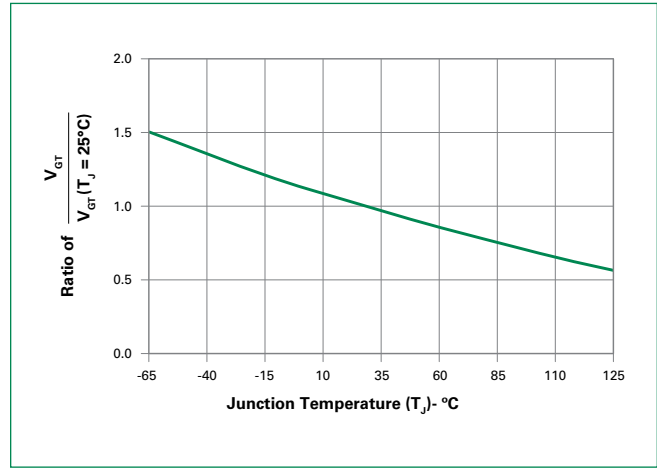


Figure 5: Power Dissipation (Typical) vs. RMS On-State Current

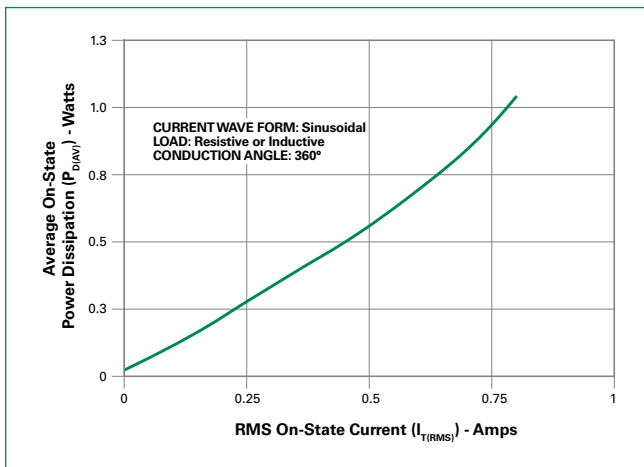


Figure 6: Maximum Allowable Case Temperature vs. On-State Current

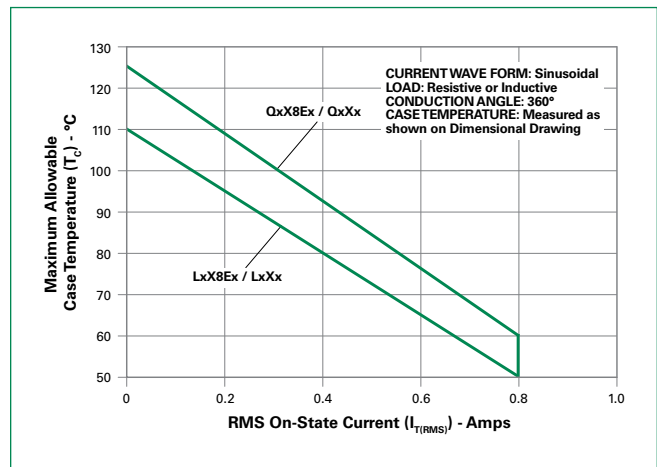


Figure 7: Maximum Allowable Ambient Temperature vs. On-State Current

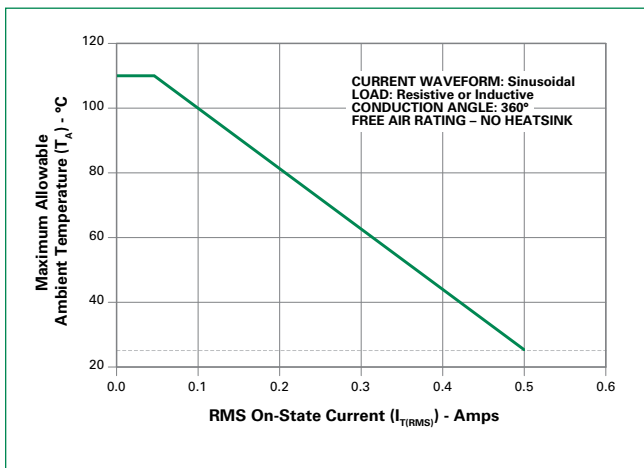


Figure 8: On-State Current vs. On-State Voltage (Typical)

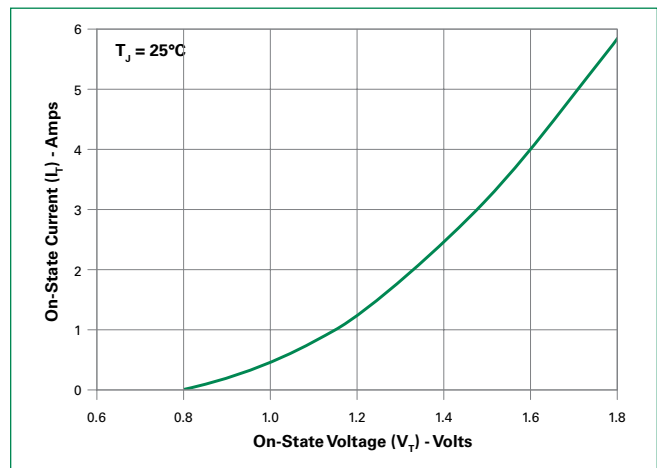
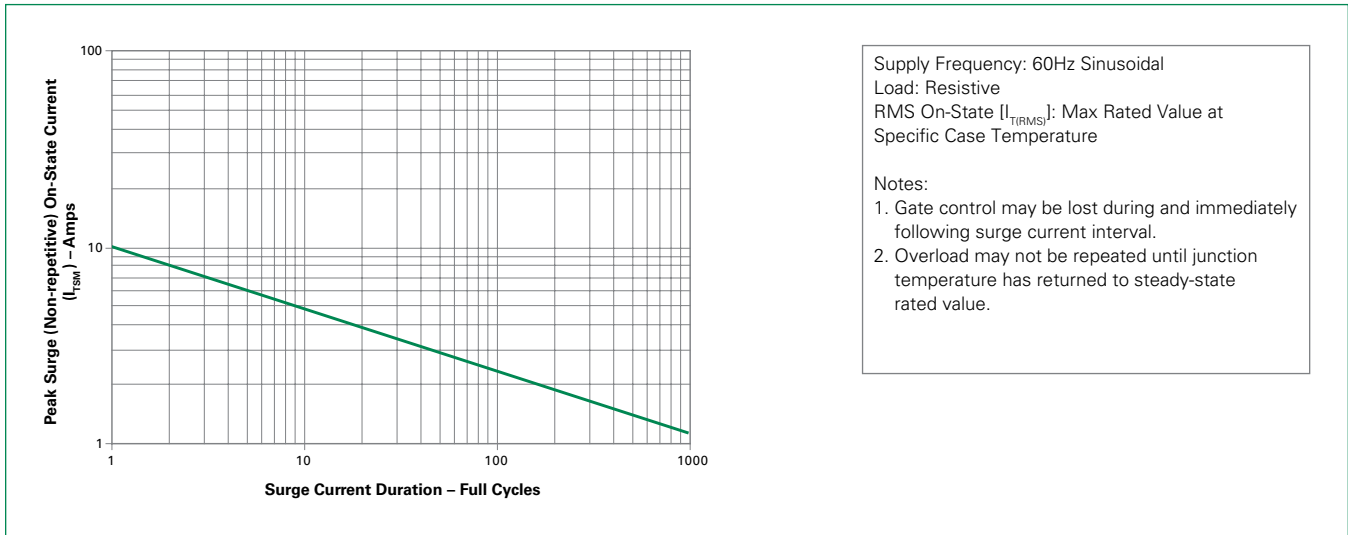
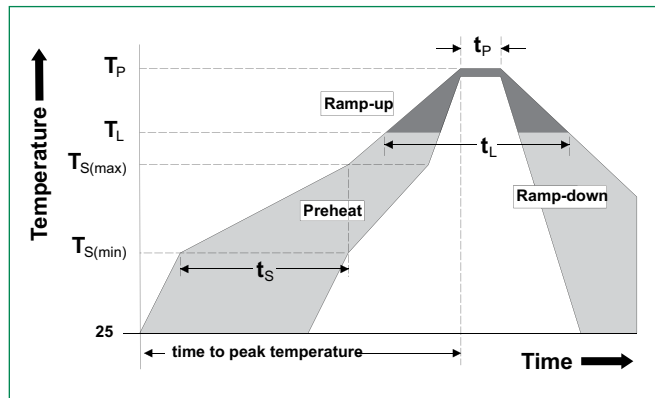


Figure 9: Surge Peak On-State Current vs. Number of Cycles



Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	- Temperature Min ($T_{s(min)}$)	150°C
	- Temperature Max ($T_{s(max)}$)	200°C
	- Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus Temp) (T_L) to peak		5°C/second max
$T_{s(max)}$ to T_L - Ramp-up Rate		5°C/second max
Reflow	- Temperature (T_L) (Liquidus)	217°C
	- Temperature (t_L)	60 – 150 seconds
Peak Temperature (T_p)		260 ^{+0/-5} °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		5°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes Max.
Do not exceed		280°C



Physical Specifications

Terminal Finish	100% Matte Tin-plated
Body Material	UL recognized epoxy meeting flammability classification 94V-0
Lead Material	Copper Alloy

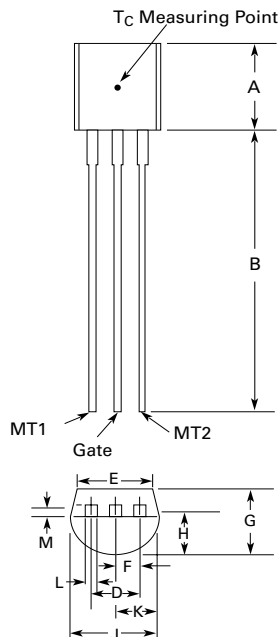
Design Considerations

Careful selection of the correct device for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the device rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

Environmental Specifications

Test	Specifications and Conditions
AC Blocking	MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 125°C for 1008 hours
Temperature Cycling	MIL-STD-750, M-1051, 100 cycles; -40°C to +150°C; 15-min dwell-time
Temperature/Humidity	EIA / JEDEC, JESD22-A101 1008 hours; 320V - DC: 85°C; 85% rel humidity
High Temp Storage	MIL-STD-750, M-1031, 1008 hours; 150°C
Low-Temp Storage	1008 hours; -40°C
Resistance to Solder Heat	MIL-STD-750 Method 2031
Solderability	ANSI/J-STD-002, category 3, Test A
Lead Bend	MIL-STD-750, M-2036 Cond E

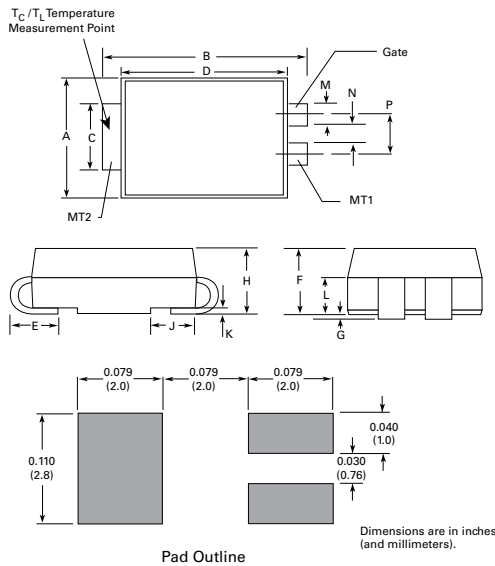
Dimensions — TO-92 (E Package)



Dimension	Inches		Millimeters	
	Min	Max	Min	Max
A	0.176	0.196	4.47	4.98
B	0.500		12.70	
D	0.095	0.105	2.41	2.67
E	0.150		3.81	
F	0.046	0.054	1.16	1.37
G	0.135	0.145	3.43	3.68
H	0.088	0.096	2.23	2.44
J	0.176	0.186	4.47	4.73
K	0.088	0.096	2.23	2.44
L	0.013	0.019	0.33	0.48
M	0.013	0.017	0.33	0.43

All leads insulated from case. Case is electrically nonconductive.

Dimensions — Compak (C Package)



Dimension	Inches		Millimeters	
	Min	Max	Min	Max
A	0.130	0.156	3.30	3.95
B	0.201	0.220	5.10	5.60
C	0.077	0.087	1.95	2.20
D	0.159	0.181	4.05	4.60
E	0.030	0.063	0.75	1.60
F	0.075	0.096	1.90	2.45
G	0.002	0.008	0.05	0.20
H	0.077	0.104	1.95	2.65
J	0.043	0.053	1.09	1.35
K	0.006	0.016	0.15	0.41
L	0.030	0.055	0.76	1.40
M	0.022	0.028	0.56	0.71
N	0.027	0.033	0.69	0.84
P	0.052	0.058	1.32	1.47

Product Selector

Part Number	Voltage		Gate Sensitivity Quadrants		Type	Package
	400V	600V	I – II – III	IV		
LxX8E3	X	X	3 mA	3 mA	Sensitive Triac	TO-92
LxX3	X	X	3 mA	3 mA	Sensitive Triac	Compak
LxX8E5	X	X	5 mA	5 mA	Sensitive Triac	TO-92
LxX5	X	X	5 mA	5 mA	Sensitive Triac	Compak
LxX8E6	X	X	5 mA	10 mA	Sensitive Triac	TO-92
LxX8E8	X	X	10 mA	20 mA	Sensitive Triac	TO-92
QxX8E3	X	X	10 mA		Standard Triac	TO-92
QxX3	X	X	10 mA		Standard Triac	Compak
QxX8E4	X	X	25 mA		Standard Triac	TO-92
QxX4	X	X	25 mA		Standard Triac	Compak

Note: x = voltage

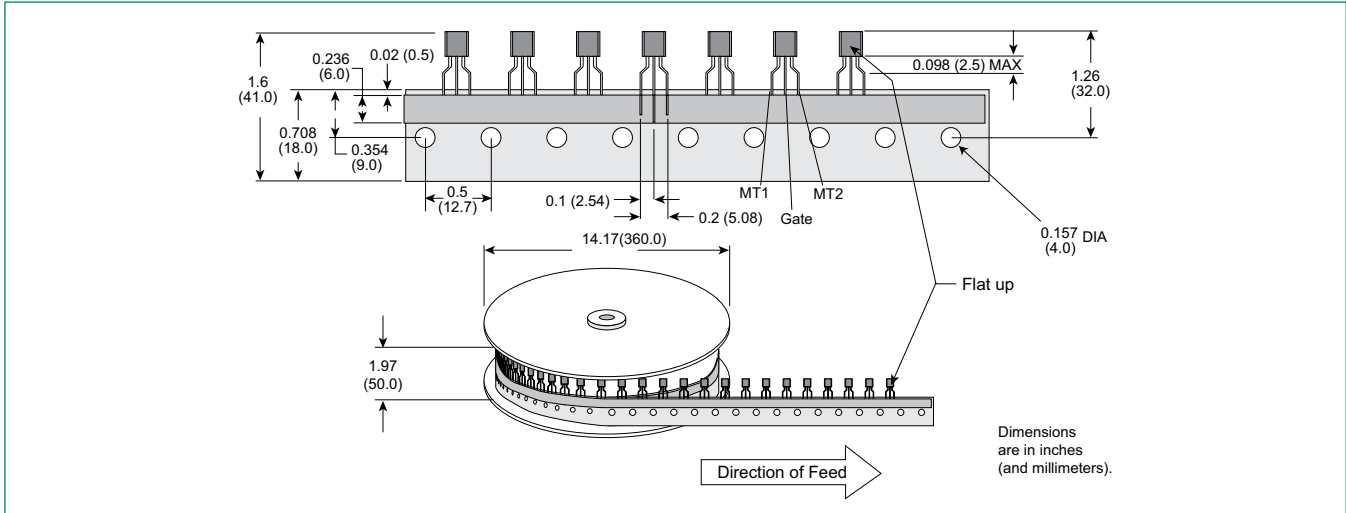
Packing Options

Part Number	Marking	Weight	Packing Mode	Base Quantity
L/QxX8Ey	L/QxX8Ey	0.188 g	Bulk	2000
L/QxX8EyRP	L/QxX8Ey	0.188 g	Reel Pack	2000
L/QxX8EyAP	L/QxX8Ey	0.188 g	Ammo Pack	2000
L/QxXyRP	L/QxXy	0.081 g	Embossed Carrier	2500

Note: x = voltage, y = sensitivity

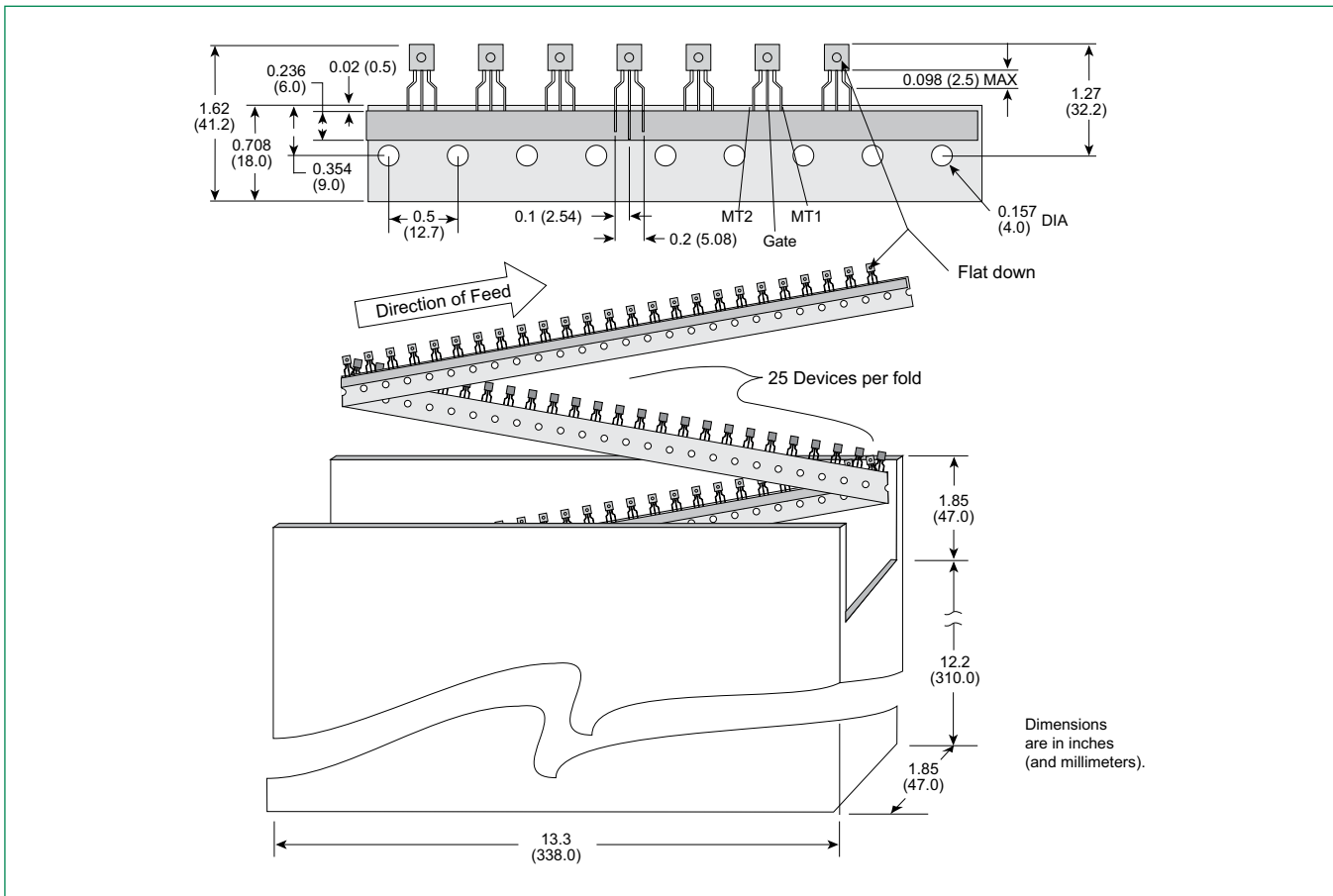
TO-92 (3-lead) Reel Pack (RP) Radial Leaded Specifications

Meets all EIA-468-C Standards



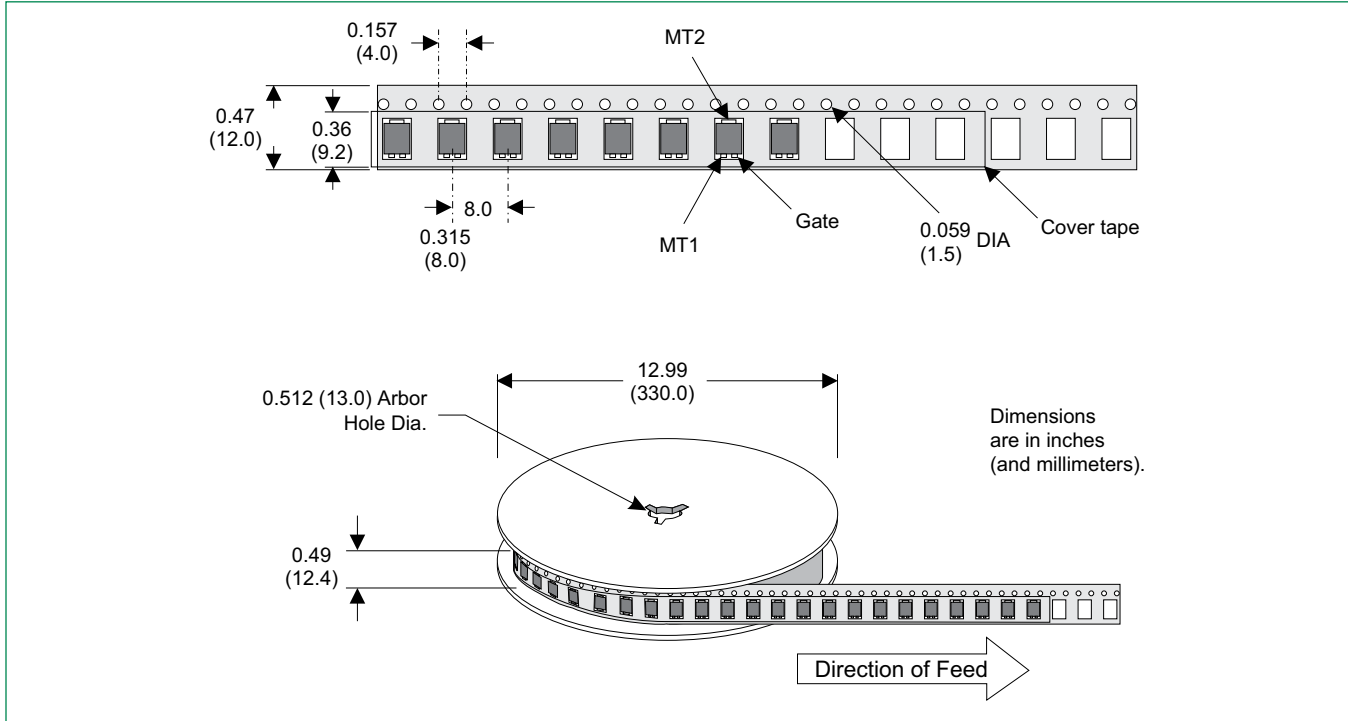
TO-92 (3-lead) Ammo Pack (AP) Radial Leaded Specifications

Meets all EIA-468-C Standards

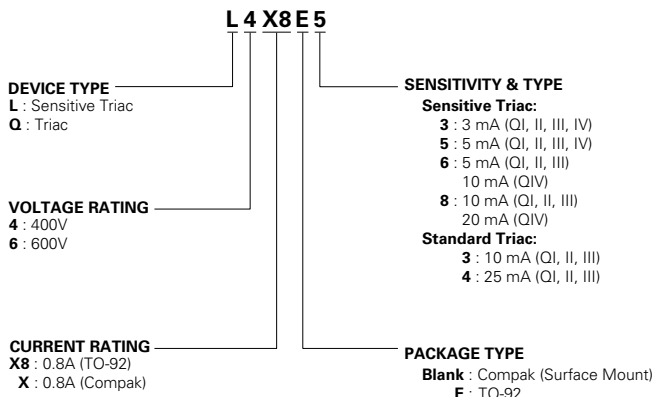


Compak Embossed Carrier Reel Pack (RP) Specifications

Meets all EIA-481-1 Standards

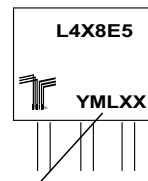


Part Numbering System



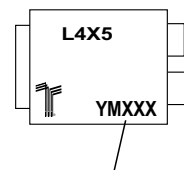
Part Marking System

TO-92 (E Package)



Date Code Marking
Y: Year Code
M: Month Code
L: Location Code
XX: Lot Serial Code

Compak (C Package)



Date Code Marking
Y: Year Code
M: Month Code
XXX: Lot Trace Code

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